

**Metric Prefixes**

peta	P	$10^{15}$	1 000 000 000 000 000
tera	T	$10^{12}$	1 000 000 000 000
giga	G	$10^9$	1 000 000 000
mega	M	$10^6$	1 000 000
kilo	k	$10^3$	1 000
hecto	h	$10^2$	100
deca	da	$10^1$	10
one		$10^0$	1
deci	d	$10^{-1}$	0.1
centi	c	$10^{-2}$	0.01
milli	m	$10^{-3}$	0.001
micro	$\mu$	$10^{-6}$	0.000 001
nano	n	$10^{-9}$	0.000 000 001
pico	p	$10^{-12}$	0.000 000 000 001
femto	f	$10^{-15}$	0.000 000 000 000 001

**Ohm's Law**  $V = IR$ ,  $I = \frac{V}{R}$ ,  $R = \frac{V}{I}$

**Complex Numbers**

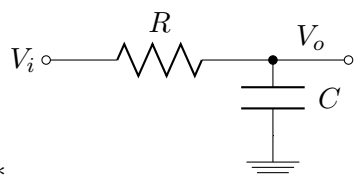
- $z = x + iy = re^{i\theta} = r[\cos(\theta) + i\sin(\theta)]$
- $[r(\cos(\theta) + i\sin(\theta))]^n = r^n[\cos(n\theta) + i\sin(n\theta)]$
- $z^n = (re^{i\theta}) = r^n e^{in\theta}$
- $\frac{1}{i} = -i$
- $\sqrt[n]{z} = \sqrt[n]{r} e^{\frac{\theta}{n} + \frac{2k\pi}{n}}$  for  $n \in \mathbb{N}^*$  (ints  $\geq 0$ )
- $e^{j\theta} = \cos(\theta) + j\sin(\theta)$
- $e^{-j\theta} = \cos(\theta) - j\sin(\theta)$
- $\cos(\theta) = \frac{1}{2}(e^{j\theta} + e^{-j\theta})$
- $\sin(\theta) = \frac{1}{2j}(e^{j\theta} - e^{-j\theta})$
- normalized:  $\text{sinc}(t) = \frac{\sin(\pi t)}{\pi t}$
- $|\frac{a}{b}| = \frac{|a|}{|b|}$
- $\angle \frac{a}{b} = \angle a - \angle b$

**Trig**

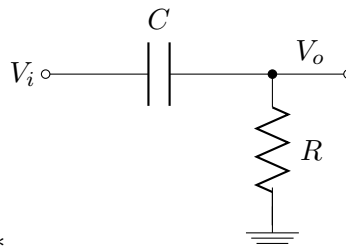
- $\cos^2(a) + \sin^2(a) = 1$
- $\cos(2a) = \cos^2(a) - \sin^2(a) = 2\cos^2(a) - 1 = 1 - 2\sin^2(a)$
- $\sin(2a) = 2\sin(a)\cos(a)$
- $\cos^2(a) = \frac{1}{2}(1 + \cos(2a))$
- $\sin^2(a) = \frac{1}{2}(1 - \cos(2a))$

**RC Filter**

- Transmission Function:  $T(s) = \frac{V_o(s)}{V_i(s)}$
- Corner frequency: frequency  $s$  at which  $T(s) = \frac{1}{\sqrt{2}}$
- for simple circuit: ground  $\rightarrow$  source  $\rightarrow R \rightarrow C \rightarrow$  ground
  - \*  $T(s) = \frac{1}{1+RCs}$
  - \*  $|T(j\omega)| = \frac{1}{\sqrt{1+R^2C^2s^2}}$
  - \*  $|\angle T(j\omega)| = \frac{1}{\sqrt{1+R^2C^2s^2}}$
- low pass



- \*  $T(s) = \frac{V_o}{V_i} = \frac{1}{1+RCs}$
- \* corner frequency:  $s = \frac{1}{RC}$  (also pole)
- \* pole:  $\frac{1}{RC}$
- high pass



- \*  $T(s) = \frac{V_o}{V_i} = \frac{RCs}{1+RCs}$
- \* zero:  $s = 0$ , pole:  $s = \frac{1}{RC}$

**Bode Plots**

- magnitude is plotted in dB:
  - \*  $|T(j\omega)|_{dB} = 20 \log_{10} |T(j\omega)|$
- starts on y-axis at DC offset with slope 0
- just add together the bode plots of each individual pole, zero, and the DC offset
- poles always slope down, zeros slope up (applies for both magnitude and phase)
- dec=decade, e.g. from  $10^0$  to  $10^1$
- magnitude:
  - \* Pole/Zero at origin: constant slope  $\pm 20\text{dB/dec}$  for all  $\omega$ ;  $0\text{dB}$  at  $\omega = 10^0 = 1$
  - \* Pole/Zero at  $\omega_0$ :
    - 0 for  $\omega < \omega_0$
    - slope  $\pm 20 \frac{\text{dB}}{\text{dec}}$  after
  - \* Constant C: constant line at  $20 \log_{10}(|C|)$
- phase:
  - \* Pole at origin: constant  $-\frac{\pi}{2}$  or  $-90^\circ$
  - \* Zero at origin: constant  $+\frac{\pi}{2}$  or  $+90^\circ$
  - \* Pole/Zero at  $\omega_0$ :
    - 0 for  $\omega < \frac{\omega_0}{10}$
    - slope linearly ( $\pm 45^\circ/\text{dec}$ ) until  $10\omega_0$
    - 0 slope for  $\omega > 10\omega_0$
  - \* Constant C: no effect (0 for all  $\omega$ )
- Prof wants us to actually show the -3dB drop curve, not just a straight intersection

**Solving systems with Op Amps**

- step 0: if the op amp is ideal, write out ideal properties:
  - \*  $V_+ = V_-$
  - \*  $I_- = 0, I_+ = 0$
  - \*  $A \approx \infty$
- avoid doing KCL/KVL directly on the output node of the op amp
- ignore resistors from a point at 0V to ground
- **Non-Ideal Op Amps**
  - still assume that current at input terminals is 0
  - $V_o = A(V_+ - V_-)$ 
    - \* A: open-loop gain. Typically very large, 100,000 or more
  - open-loop gain dependent on frequency:  $A(s) = \frac{A_0}{1 - \frac{s}{\omega_b}}$ 
    - \* open-loop response drops off after  $\omega_b$  (usually  $2\pi \leq \omega_b \leq 2\pi 100$ )
    - \*  $A_0$ : DC gain
    - \*  $\omega_t$ : unity gain frequency:  $\text{dB}(T(\omega_t)) = 1$
    - $\omega_t \approx A_0 \omega_b$
    - AKA gain bandwidth product
    - \* in this case, we still assume  $I_- = I_+ = 0$  and  $V_- = V_+$ ?
- slew rate
  - \* max rate at which the output can change
  - \* for a sinusoidal signal: ( $V_{pk}$ : peak voltage)
    - $SR > 2\pi f V_{pk}$  or  $SR > \omega V_{pk}$
  - $\frac{dV_o}{dt}|_{MAX} < SR$

**Op Amp Equations**

- general form:  $T(s) = \frac{K_0 s}{1 + \frac{s}{\omega_0}}$

\*  $T(0) = K_0$ : DC offset. For these simple ones, it's equal to ideal response

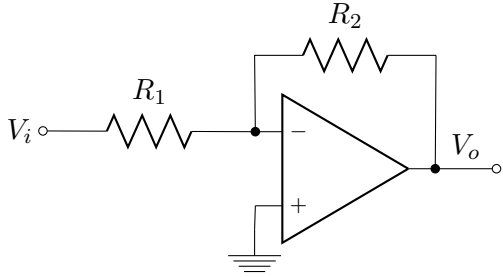
\*  $\omega_0 = \frac{\omega_t}{1 + R_2/R_1}$

- inverting op amp:

\* ideal:  $T(s) = \frac{V_o}{V_i} = -\frac{R_2}{R_1}$

\* non-ideal:

$$T(s) = \frac{V_o}{V_i} = \frac{-R_2/R_1}{1 + \frac{1+R_2/R_1}{A(s)}} = \frac{-R_2/R_1}{1 + \frac{s}{\left(\frac{\omega_t}{1+R_2/R_1}\right)}} = \frac{-R_2/R_1}{1 + \frac{s}{\omega_0}}$$

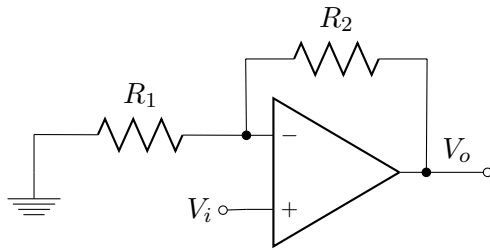


- non-inverting op-amp:

\* ideal:  $T(s) = \frac{V_o}{V_i} = 1 + \frac{R_2}{R_1}$

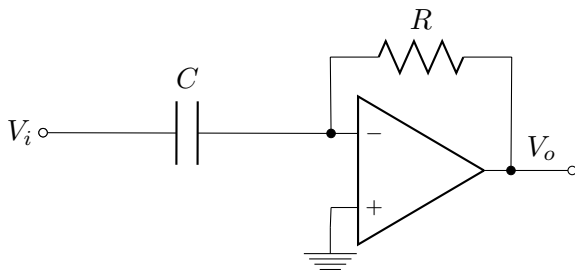
\* non-ideal:

$$T(s) = \frac{V_o}{V_i} = \frac{1+R_2/R_1}{1 + \frac{1+R_2/R_1}{A(s)}} = \frac{1+R_2/R_1}{1 + \frac{s}{\left(\frac{\omega_t}{1+R_2/R_1}\right)}} = \frac{1+R_2/R_1}{1 + \frac{s}{\omega_0}}$$



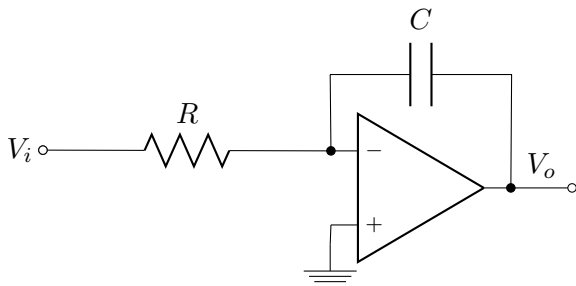
- integrating

\* ideal:  $V_o = -\int_0^t \frac{V_i}{RC} dt + C$   
 $= C = V_o(t)$  at  $t = 0$



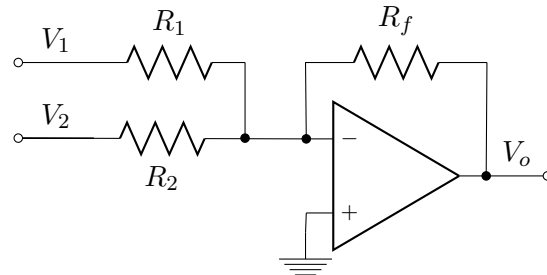
- differentiating

\* ideal:  $V_o = -RC \frac{dV_i}{dt}$



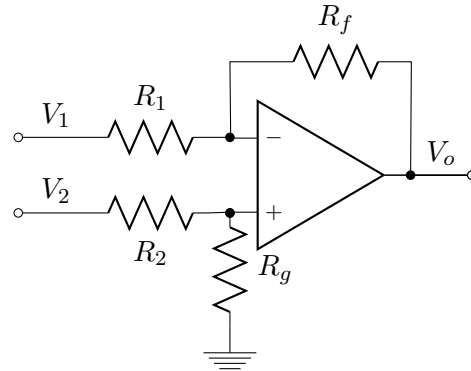
- summing

\* ideal:  $V_o = -R_f \left( \frac{V_1}{R_1} + \frac{V_2}{R_2} \right)$



- differential (subtracting)

\* ideal:  $V_o = \frac{(R_f + R_1)R_g}{(R_g + R_2)R_1} V_2 - \frac{R_f}{R_1} V_1$



## Diodes

•  $I_D = I_S \left( e^{\frac{V_D}{nV_T}} - 1 \right)$

\*  $I_S = 10^{-12} \text{ A}$  (saturation current)

\*  $V_T = 25 \text{ mV}$

- small signal resistance:  $R_D = \frac{nV_T}{I_D}$

\*  $I_D$ : average (DC) current through diode (due to forward bias)

- bridge rectifier shape: all the diodes point toward the + end of the output (away from ground)

## Design an (unregulated) AC adapter

- $V_S$ : AC voltage input

- $V_{S2}$ : output of transformer (still AC)

- $V_p$ : peak DC output

\*  $V_r$ : peak-to-peak ripple voltage (maximum variation)

- $V_p = V_{S2} -$  (diode voltage)

\* diode voltage = 0.7V for single wave rectifier or center-tapped transformer

\* diode voltage = 1.4V for full-wave rectifier

- turns ratio =  $n = \frac{V_S}{V_{S2}}$

- apparent load resistance:  $R_L = \frac{V_o}{I_L}$

- ripple voltage:  $V_r = \frac{f}{R_L C}$

\*  $f$ : actual ripple frequency (double for full-wave rectifier)

\*  $C$ : filter cap size

- Peak Inverse Voltage:  $PIV = V_{S2} - 0.7V$

- avg diode current:  $I_{Davg} = I_L \left( 1 + \pi \sqrt{\frac{2}{V_r}} \right)$

- max diode current:  $I_{Dmax} = I_L \left( 1 + 2\pi \sqrt{\frac{2}{V_r}} \right)$

\* only difference is  $\pi \rightarrow 2\pi$

## Transistors

- $V_T = 25 \text{ mV}$  at room temperature (according to textbook and prof),

$V_T = 26 \text{ mV}$  at room temperature (according to lab)

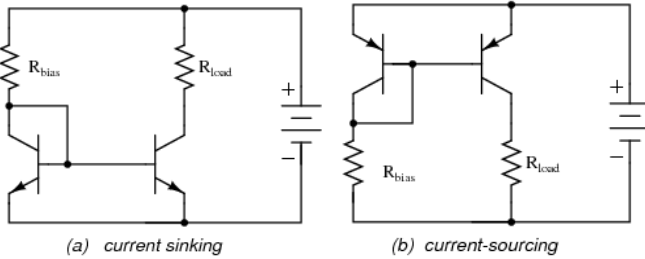
- $\beta$ : a physical constant of the transistor. Usually about 100 or 200

- $I_B + I_C = I_E$ ,  $I_C = \beta I_B$ ,  $I_E = (1 + \beta) I_B$

- $\alpha = \frac{\beta}{1 + \beta}$ ,  $I_C = \alpha I_E$

- $I_C = I_S(e^{\frac{V_{BE}}{nV_T}})$ ,
- AC (assumes correct DC bias):  $g_m = \frac{1}{r_e} = \frac{I_C}{V_T}$

### Current Mirror



- Q1 has the base shorted to collector, Q2 does not
- $R_{bias} = R_{ref}$ : the current that is mirrored
- $I_{ref} = (V_{CC} - 0.7)/R_{ref}$
- $R_{load}$  has the same current through it as  $R_{ref}$  does
  - \* that is,  $I_{ref} = I_{load}$
- you can chain together multiple transistors (Q3, Q4...) all off of the same Q1 and they will all get the same current
  - \* In this case, each Q2, Q3... output is considered separate from each other in both DC and AC analysis
- only applies when transistors are matched! (we assume they are)

### Transistor circuits by inspection

- this all assumes that the transistor is properly DC biased
- three types of amplifier circuits: common emitter, common base, common collector
  - \* CE, CB, CC
  - \* the “common” pin is the one that is neither AC input nor output
- intrinsic gain: gain directly from the input pin of the transistor to the output, ignoring any source resistance or such things whatever
  - \* when you chain multiple amplifiers together, this is the one you use
- when you’re driving a finite-impedance load (a load other than open circuit), you have to consider  $R_o$  as  $R_o || R_L$ 
  - \* this will change the gain, which is why it’s often helpful to put a CC buffer at the end of an amplifier
- $R_i$ : input impedance: impedance as seen from the input
  - \* includes the transistor, does not include  $R_s$
- $g_m = \frac{I_C}{V_T}$
- $r_\pi = \frac{\beta}{g_m}$
- $r_e = \frac{V_T}{I_E} = \frac{\alpha}{g_m} \approx \frac{1}{g_m}$
- $r_o = \frac{V_A}{I_C} \approx \infty$
- TODO pictures!
- CE: Common Emitter
  - \* input: base; output: collector
  - \* intrinsic gain:  $\frac{V_o}{V_b} = -\alpha \frac{R_C}{r_e + R_E} \approx -\frac{R_C}{r_e + R_E}$
  - \*  $R_i = (\beta + 1)(r_e + R_E)$
  - \*  $R_o = R_C$
  - \* if you have a  $R_L$  then you have to put that in parallel with  $R_C$  when calculating  $\frac{V_o}{V_b}$
- CB: Common Base
  - \*  $\frac{V_o}{V_b} = \alpha \frac{R_C}{R_i} \approx \frac{R_C}{R_i}$
  - \*  $R_i = r_e + \frac{R_B}{\beta + 1}$
  - \*  $R_o = R_C$
- CC: Common Collector
  - \* gain  $\approx 1$  because it’s a buffer

$$\begin{aligned}
 * \frac{V_o}{V_b} &= \frac{R_E}{r_e + R_E} \\
 * R_i &= (\beta + 1)(r_e + R_E) \\
 * R_o &= R_E || r_e = \frac{R_E * r_e}{R_E + r_e}
 \end{aligned}$$